

CLC1200

Instrumentation Amplifier

General Description

The CLC1200 is a low power, general purpose instrumentation amplifier with a gain range of 1 to 10,000. The CLC1200 is offered in 8-lead SOIC or DIP packages and requires only one external gain setting resistor making it smaller and easier to implement than discrete, 3-amp designs.

While consuming only 2.2mA of supply current, the CLC1200 offers a low 6.6nV/Hz input voltage noise and 0.2µVpp noise from 0.1Hz to 10Hz.

The CLC1200 offers a low input offset voltage of $\pm 125\mu V$ that only varies 0.1 μV /°C over it's operating temperature range of -40°C to +85°C. The CLC1200 also features 50ppm maximum nonlinearity. These features make it well suited for use in data acquisition systems.

FEATURES

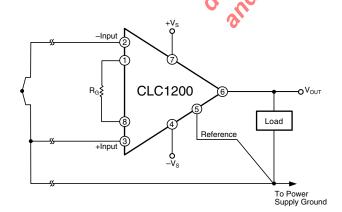
- ±2.3V to ±18V supply voltage range
- Gain range of 1 to 10,000
- Gain set with one external resistor
- ±125µV maximum input offset voltage
- 0.1µV/°C input offset drift
- 700kHz bandwidth at G = 1
- 1.2V/µs slew rate
- 90dB minimum CMRR at G = 10
- 2.2mA maximum supply current
- 6.6nV/JHz input voltage noise
- 70nV/JHz output voltage noise
- №0.2μV_{pp} input noise (0.1Hz to 10Hz)
- DIP-8 or Pb-free SOIC-8

APPLICATIONS

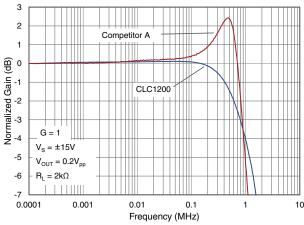
- Bridge amplifier
- Weigh scales
- Thermocouple amplifier
- ECG and medical instrumentation
- MRI (Magnetic Resonance Imaging)
- Patient monitors
- Transducer interface
- Data acquisition systems
- Strain gauge amplifier
- Industrial process controls

Ordering Information - back page

Typical Application



Competitive Plot



Thermocouple Amplifier

Absolute Maximum Ratings

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Supply Voltage±18\
Input Voltage Range ±V _S \
Differential Input Voltage (G = 1 to 10)
Differential Input Voltage (G > 10) \leq 0.05 (R _G + 800) +1 V
Load Resistance (min)

Operating Conditions

Supply Voltage Range	±2.3V to ±18V (4.6V to 36V)
Gain Range	1 to 10,000
Operating Temperature Range	40°C to 85°C
Junction Temperature	150°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering, 10s).	260°C

θ _{JA} (DIP-8)100°C/W
θ_{JA} (SOIC-8)150°C/W
Package thermal resistance (θ_{JA}), JEDEC standard, multi-laye test boards, still air

Al Resis

thermal resistarice (θ_{JA}),
ards, still air

ESD Protection

SOIC-8 (μBM)

ESD Bating for HBM (Human Body Model).

Electrical Characteristics

 $T_A = 25^{\circ}\text{C}, \ V_S = \pm 15\text{V}, \ R_L = 2\text{k}\Omega \ \text{to GND}; \ \text{unless otherwise noted}. \ \text{Gain} = 1 + (49.4\text{k/R}_{\text{G}}); \ \text{Total RTI Error} = V_{OSI} + (V_{OSO}/G)$

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Gain						
	Gain Range		1		10,000	
		$G = 1, V_{OUT} = \pm 10V$	-0.1		0.1	%
	Coin Favor (1)	$G = 10, V_{OUT} = \pm 10V$	-0.375		0.375	%
	Gain Error (1)	G = 100, V _{OUT} = ±10V	-0.375		0.375	%
		$G = 1,000, V_{OUT} = \pm 10V$	-0.8		0.8	%
	Gain Nonlinearity	G = 1 - 100, V_{OUT} = -10V to 10V, R_L = 10kΩ		10	50	ppm
	dair Nominearty	$G = 1 - 100$, $V_{OUT} = -10V$ to 10V, $R_L = 2k\Omega$		10	95	ppm
	Gain vs. Temperature	G = 1		<10		ppm/°C
	dain vs. remperature	G>1)	<-50		ppm/°C
	Reference Gain Error ⁽¹⁾	$V_S = \pm 16.5V$	-0.03		0.03	%
Voltage Offs	set	10 10	,			
V _{OSI}	Input Offset Voltage	$V_S = \pm 4.5 \text{V to } \pm 16.5 \text{V}$	-125		125	μV
	Average Temperature Coefficient	$V_S = \pm 4.5 \text{V to } \pm 16.5 \text{V}$ $V_S = \pm 4.5 \text{V to } \pm 16.5 \text{V}, G$		0.1		μV/°C
V _{OSO}	Output Offset Voltage		-1500	200	1500	μV
	Average Temperature Coefficient	$V_S = \pm 4.5 \text{V to } \pm 16.5 \text{V}$		2.5		μV/°C
		$G = 1, V_S = \pm 2.3V \text{ to} \pm 18V$	80	100		dB
PSR	Offset Referred to the Input vs. Supply	$G = 10, V_S = \pm 2.3 V \text{ to } \pm 18 V$	95	120		dB
	,	$G = 100, V_S = \pm 2.3V \text{ to } \pm 18V$	110	140		dB
		G = 1000, V _S = ±2.3V to ±18V	110	140		dB
Input Curre		70 90 70				_
I _B	Input Bias Current	V _S = 16.5V	-2	0.5	2	nA
	Average Temperature Coefficient	V _S =±16.5V	<u> </u>	3		pA/°C
l _{OS}	Input Offset Current	$V_S = \pm 16.5 V$	-1		1	nA
Input			<u> </u>		I	
	Input Impedance	Differential		10, 2		GΩ, pF
	W	Common-Mode	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	10, 2)/ 10	GΩ, pF
IVR	Input Voltage Range (2)	V _S =±4.5V, G = 1	-V _S + 1.9		+V _S - 1.2	V
	IVR Input Voltage Range (2)	$V_S = \pm 16.5V, G = 1$	-V _S + 1.9		+V _S - 1.4	V
		$G = 1, V_S = \pm 16.5V$	70	90		dB
CMRR	Common-Mode Rejection Ratio	$G = 10, V_S = \pm 16.5V$ $G = 100, V_S = \pm 16.5V$	90	110		dB
	Common-Mode Rejection Ratio		108	130		dB
Output	ॐ	G = 1000, V _S = ±16.5V	108	130		dB
Output		V _S = ±2.3V to ±4.5V	-V _S + 1.1		+V _S - 1.2	V
V_{OUT}	Output Swing	V _S = ±18V, G = 1	$-V_S + 1.1$ $-V_S + 1.4$		+V _S - 1.2	V
I _{SC}	Short Circuit Current	VS = ±10V, CI = 1	75 + 1.4	±20	TVS 1.2	mA
Dynamic Pe		<u></u>				111/3
Dynamic i e	Sicination	G = 1		700		kHz
	Small Signal -3dB Bandwidth	G = 10		400		kHz
BW _{-3dB}		G = 100		100		kHz
				12		kHz
		G = 1000				
SR	Slew Rate	G = 1000 G = 10. Vs = ±15V	0.6			
SR	Slew Rate	G = 1000 $G = 10, V_S = \pm 15V$ 5V step, $G = 1$ to 100	0.6	1.2		V/µs µs

Electrical Characteristics continued

 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2k\Omega$ to GND; unless otherwise noted. Gain = 1 + (49.4k/R_G); Total RTI Error = V_{OSO}/G)

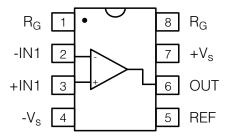
eak-to-Peak Noise Furrent Noise eak-to-Peak Current Noise	$1kHz, G = 1000, V_S = \pm 15V$ $1kHz, G = 1, V_S = \pm 15V$ $G = 1, 0.1Hz \text{ to } 10Hz$ $G = 10, 0.1Hz \text{ to } 10Hz, V_S = \pm 15V$ $G = 100, 0.1Hz \text{ to } 10Hz, V_S = \pm 15V$ $f = 1kHz$ $0.1Hz \text{ to } 10Hz$		6.6 70 5 0.2	13 100 0.8 0.4	nV/√Hz nV/√Hz µV _{pp} µV _{pp}
eak-to-Peak Noise Furrent Noise eak-to-Peak Current Noise	1kHz, G = 1, $V_S = \pm 15V$ G = 1, 0.1Hz to 10Hz G = 10, 0.1Hz to 10Hz, $V_S = \pm 15V$ G = 100, 0.1Hz to 10Hz, $V_S = \pm 15V$ f = 1kHz		70 5 0.2	0.8	nV/√Hz μV _{pp} μV _{pp}
eak-to-Peak Noise (RTI) Furrent Noise eak-to-Peak Current Noise	G = 1, 0.1Hz to 10Hz $G = 10$, 0.1Hz to 10Hz, $V_S = \pm 15V$ $G = 100$, 0.1Hz to 10Hz, $V_S = \pm 15V$ f = 1kHz		0.2	0.8	μV _{pp} μV _{pp}
eak-to-Peak Current Noise	G = 10, 0.1Hz to 10Hz, $V_S = \pm 15V$ G = 100, 0.1Hz to 10Hz, $V_S = \pm 15V$ f = 1kHz		0.2		μV_{pp}
eak-to-Peak Current Noise	$G = 100, 0.1Hz \text{ to } 10Hz, V_S = \pm 15V$ f = 1kHz				
eak-to-Peak Current Noise	f = 1kHz			0.4	μV _{nn}
eak-to-Peak Current Noise			100		, י אר
	0.1Hz to 10Hz				fA/√Hz
			10		pA _{pp}
put Resistance				'	- ''
		9	20		kΩ
put Current	$V_S = \pm 16.5V$		50	60	μA
oltage Range	in city	-V _S + 1.6		+V _S - 1.6	V
ain to Output	9 80	-	1±0.0001		
·	76 VII				
perating Range	:0 all	±2.3		±18	V
upply Current	$V_{S} = \pm 16.5 V$		1.3	2.2	mA
Theproduc	thay not be ordered.				
)	ain to Output	perating Range upply Current V _S = ±16.5V	ain to Output	ain to Output 1±0.0001	ain to Output 1±0.0001

Notes:

^{1.} Nominal reference voltage gain is 1.0

^{2.} Input voltage range = $CMV + (G V_{DIFF})/2$

CLC1200 Pin Configurations SOIC-8, DIP-8



CLC1200 Pin Assignments

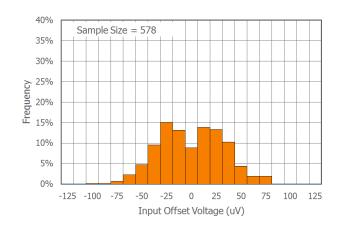
SOIC-8, DIP-8

Pin No.	Pin Name	Description
1, 8	R _G	R _G sets gain
2	-IN	Negative input
3	+IN	Positive input
4	-V _S	Negative supply
5	REF	Output is referred to the REF pin potential
6	OUT	Output
7	+V _S	Positive supply

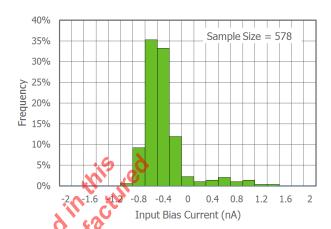
Posit.

 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2k\Omega$ to GND; unless otherwise noted.

Input Offset Distribution (typical)



Input Bias Current Distribution (typical)

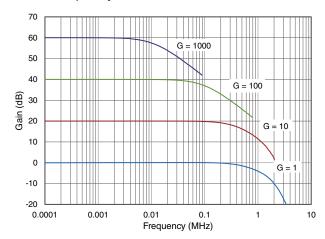


Input Offset Current Distribution (typical)

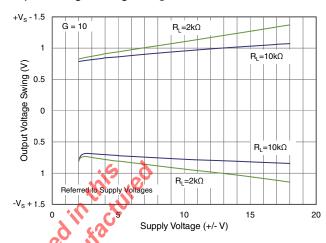


 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2k\Omega$ to GND; unless otherwise noted.

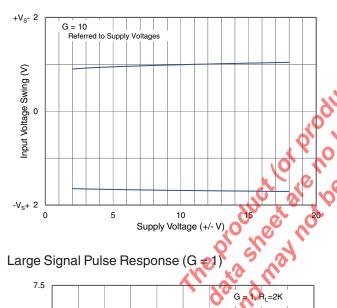
Gain vs. Frequency



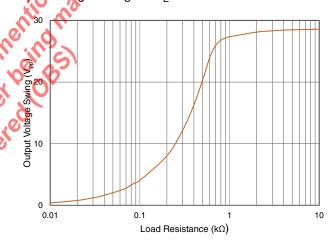
Output Voltage Swing vs. VS

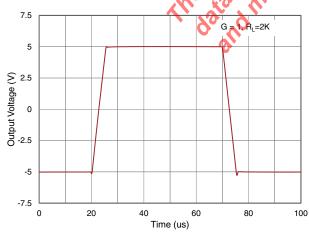


Input Voltage Range vs. VS

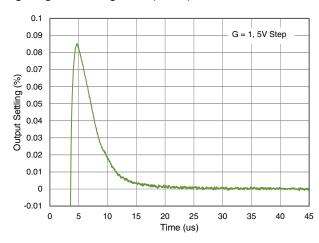


Output Voltage Swing vs. R_L



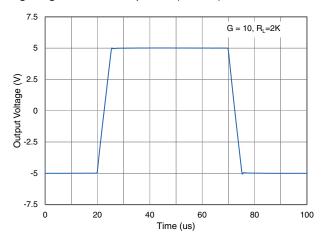


Large Signal Settling Time (G = 1)

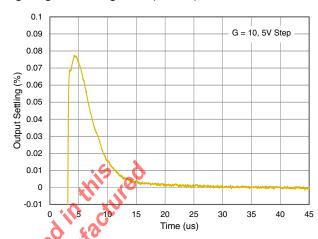


 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2k\Omega$ to GND; unless otherwise noted.

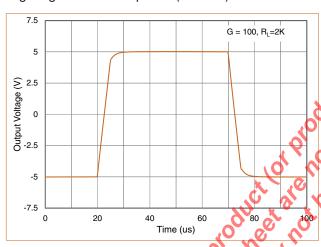
Large Signal Pulse Response (G = 10)



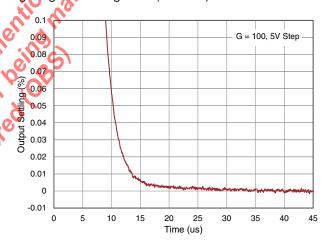
Large Signal Settling Time (G = 10)

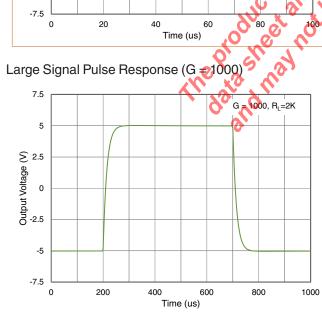


Large Signal Pulse Response (G = 100)

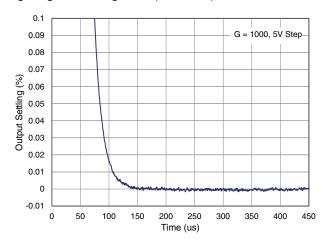


Large Signal Settling Time (G = 100)



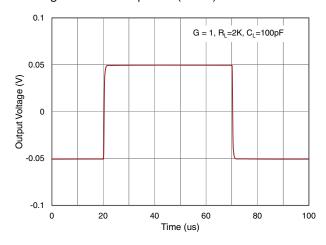


Large Signal Settling Time (G = 1000)

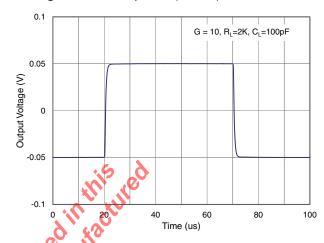


 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2k\Omega$ to GND; unless otherwise noted.

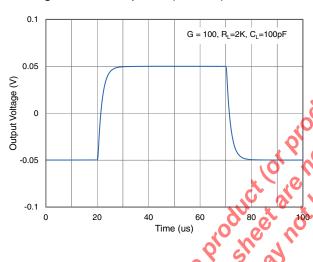
Small Signal Pulse Response (G = 1)



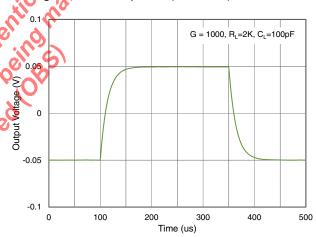
Small Signal Pulse Response (G = 10)



Small Signal Pulse Response (G = 100)



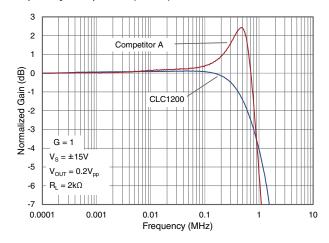
Small Signal Pulse Response (G = 1000)



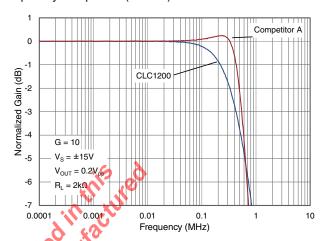
Typical Competitive Comparison Plots

 $T_A = 25$ °C, $V_S = \pm 15$ V, $R_L = 2$ k Ω , Exar evaluation board; unless otherwise noted.

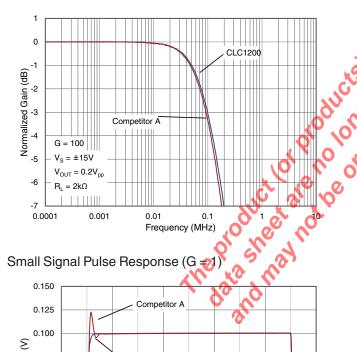
Frequency Response (G = 1)



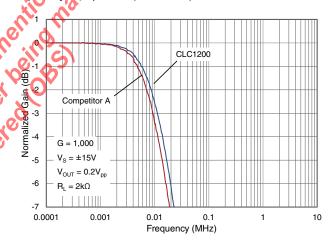
Frequency Response (G = 10)

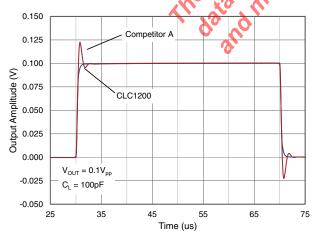


Frequency Response (G = 100)

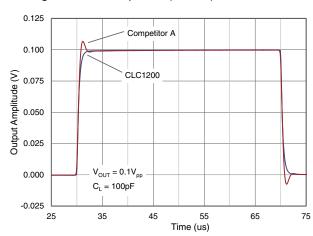


Frequency Response (G = 1000)





Small Signal Pulse Response (G = 10)



Application Information

Basic Information

The CLC1200 is a monolithic instrumentation amplifier based on the classic three op amp solution, refer to the Functional Block Diagram shown in Figure 1. The CLC1200 produces a single-ended output referred to the REF pin potential.

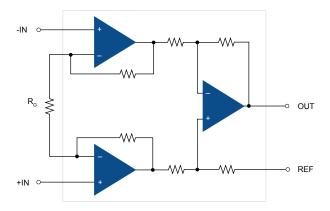


Figure 1: Functional Block Diagram

The internal resistors are trimmed which allows the gain to be accurately adjusted with one external resistor $R_{\rm G}$.

$$G = \frac{49.4k}{R_G} + 1$$
; $R_G = \frac{49.4k}{G - 1}$

 R_G also determines the transconductance of the preamp stage. As R_G is reduced for larger gains, the transconductance increases to that of the input transistors. Producing the following advantages:

- Open-loop gain increases as the gain is increased, reducing gain related errors
- Gain-bandwidth increases as the gain is increased, optimizing frequency response
- Reduced input voltage noise which is determined by the collector current and base resistance of the input devices

Gain Selection

The impedance between pins 1 and 8, R_G , sets the gain of the CLC1200. Table 1 shows the required standard table values of R_G for various calculated gains. For G = 1, $R_G = \infty$.

1% R _G (Ω)	Caclulated Gain	0.1% R _G (Ω)	Calculated Gain
49.9k	1.990	49.3k	2.002
12.4k	4.984	12.4k	4.984
5.49k	9.998	5.49k	9.998
2.61k	19.93	2.61k	19.93
1.00k	50.40	1.01k	49.91
499	100.0	499	100.0
249	199.4	249	199.4
100	495.0	98.8	501.0
49.9	991.0	49.3	1,003.0

Table 1: Recommended R_G Values

Follow these guidelines for improved performance:

- To maintain gain accuracy, use 0.1% to 1% resistors
- To minimize gain error, avoid high parasitic resistance in series with R_G
- To minimize gain drift, use low TC resistors (<10ppm/°C)

Common Mode Rejection

The CLC1200 offers high CMRR. To achieve optimal CMRR performance:

- Connect the reference terminal (pin 5) to a low impedance
- Minimize capacitive and resistive differences between the inputs

In many applications, shielded cables are used to minimize noise. Properly drive the shield for best CMRR performance over frequency. Figures 1 and 2 show active data guards that are configured to improve AC common-mode rejections. the capacitances of input cable shields are "bootstrapped" to minimize the capacitance mismatch between the inputs.

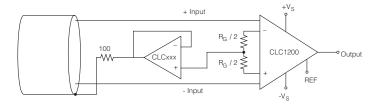


Figure 2: Common-mode Shield Driver

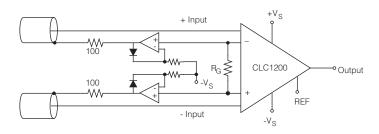


Figure 3: Differential Shield Driver

Pressure Measurement Applications

The CLC1200 is especially suitable for higher resistance pressure sensors powered at lower voltages where small size and low power become more significant.

Figure 3 shows a $3k\Omega$ pressure transducer bridge powered from 5V. In such a circuit, the bridge consumes only 1.7mA. Adding the CLC1200 and a buffered voltage divider allows the signal to be conditioned for only 3.8mA of total supply current.

Small size and low cost make the CLC1200 especially attractive for voltage output pressure transducers. Since it delivers low noise and drift, it will also serve applications such as diagnostic noninvasive blood pressure measurement.

Medical ECG

The CLC1200 is perfect for ECG monitors because of its low current noise. A typical application is shown in Figure 4. The CLC1200's low power, low supply voltage requirements, and space-saving 8-lead SOIC package offerings make it an excellent choice for battery-powered data recorders.

Furthermore, the low bias currents and low current noise, coupled with the low voltage noise of the CLC1200, improve the dynamic range for better performance.

The value of capacitor C1 is chosen to maintain stability of the right leg drive loop. Proper safeguards, such as isolation, must be added to this circuit to protect the patient from possible harm.

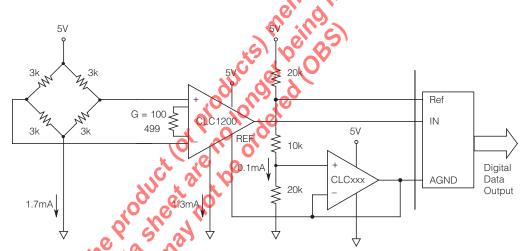


Figure 4: Pressure Monitoring Circuits Operating on a Single 5V Supply

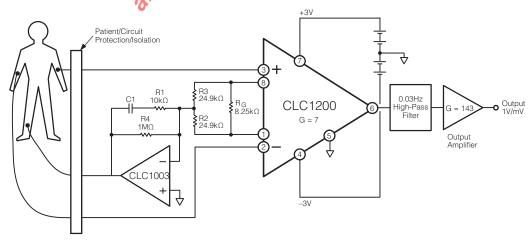


Figure 5: Typical Circuit for ECG Monitor Applications

Grounding

The output voltage of the CLC1200 is developed with respect to the potential on the reference terminal (pin 8). Simply tie the REF pin to the appropriate "local ground" to resolve many grounding problems.

To isolate low level analog signals from a noisy digital environment, many data acquisition components have separate analog and digital ground pins. Use separate ground lines (analog and digital) to minimize current flow from sensitive areas to system ground. These ground returns must be tied together at some point, usually best at the ADC.

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Exar has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.1µF ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pine
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

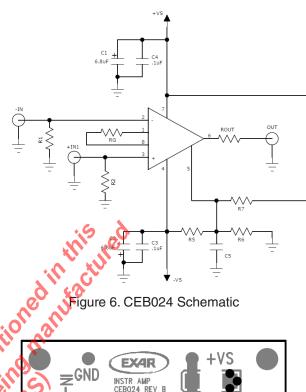
The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board #	Products
CEB024	CLC1200 in SOIC-8

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 6-8. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -V_S to ground.
- 2. Use C3 and C4, if the -V_S pin of the amplifier is not directly connected to the ground plane.



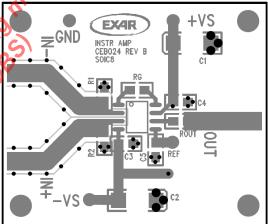


Figure 7. CEB024 Top View

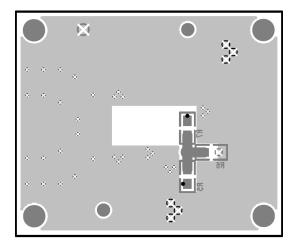
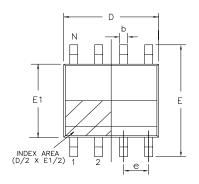


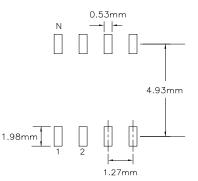
Figure 8. CEB024 Bottom View

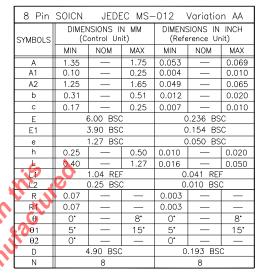
Mechanical Dimensions

SOIC-8 Package

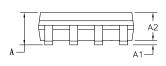


RECOMMENDED PCB LAND PATTERN

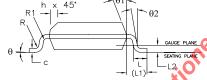




Top View

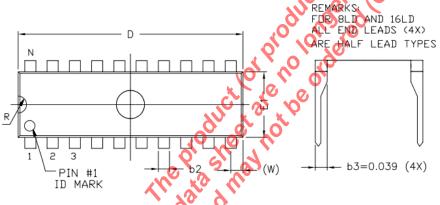


Side View

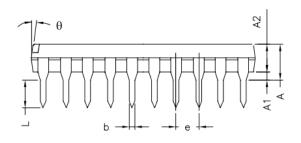


Front View

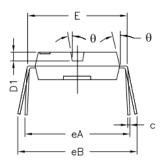
DIP-8 Package



Top View



Side View



Front View

8 Pin PDIP JEDEC MS-001 Variation BA						
SYMBOLS	DIMENSIONS IN INCH (Control Unit)			DIMENSIONS IN MM (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
A	_	_	0.210		_	5.33
A1	0.015	_	_	0.38	_	_
A2	0.115	0.130	0.195	2.92	3.30	4.95
b	0.014	0.018	0.022	0.36	0.46	0.56
b2	0.045	0.060	0.070	1.14	1.52	1.78
С	0.008	0.010	0.014	0.20	0.25	0.36
D1	0.030	_	0.060	0.76	_	1.52
E	0.300	0.310	0.325	7.62	7.87	8.26
E1	0.240	0.250	0.280	6.10	6.35	7.11
е	(0.100 E	SC	2.54 BSC		
eA	C	0.300 E	SC	7	.62 BS	C
eB	_	_	0.430	-	_	10.92
L	0.115	0.130	0.150	2.92	3.30	3.81
W	0.075 REF			1.	.91 REI	-
R	0.030 BSC			C	.76 BS	C
θ	4.	7*	10°	4*	7*	10°
D	0.355	0.365	0.400	9.02	9.27	10.16
N	8				8	

Ordering Information

Part Number	Package	Green	Operating Temperature Range	Packaging
CLC1200ISO8X	SOIC-8	Yes	-40°C to +85°C	Tape & Reel
CLC1200ISO8MTR	SOIC-8	Yes	-40°C to +85°C	Mini Tape & Reel
CLC1200ISO8EVB	Evaluation Board	N/A	N/A	N/A
CLC1200IDP8	DIP-8	Yes	-40°C to +85°C	Rail

Moisture sensitivity level for all parts is MSL-1. Mini Tape and Reel contains 250 pieces.

Revision History

Revision	Date	Description
2E (ECN 1513-02)	March 2015	Reformat into Exar data sheet template. Updated PODs and thermal resistance numbers. Updated ordering information table to include MTR and EVB part numbers. Updated evaluation board top and bottom views to Rev b. Added schematic used for evaluation boards.
	the	roduct or products in ordered (OES) roduct lare no londered (OES) roduct lare not be ordered (OES)
For Further Assistance	. 8	and
Email: CustomerSupport@exar.		
Exar Technical Documentation Exar Corporation Headquarters	•	

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